

# Half-bridge buck converter evaluation board using the EiceDRIVER™ 2EDL803x

Order code: EVAL\_HB\_2EDL803x-G3C, EVAL\_HB\_2EDL803x-G4B, EVAL\_HB\_2EDL803x-G4C

## About this document

### Scope and purpose

The 2EDL803x is the EiceDRIVER™ family designed to drive both high-side and low-side MOSFETs in a half-bridge configuration. The floating high-side driver is capable of driving a high-side MOSFET operating at up to 120 V bootstrap voltage. Version 4 provides full 4 A current capability, while version 3 provides 3 A. The high-side bias voltage is generated using a bootstrap technique with an integrated bootstrap diode. The inputs of the driver are TTL logic compatible and can withstand input common mode swing from -10 V up to 20 V. Independent inputs allow controlling high- and low-side domains independently. Undervoltage lockout (UVLO) on both high- and low-side supplies forces the corresponding outputs low in case of insufficient supply. The 2EDL803x is available in SON-8 pins 4 mm x 4 mm, SON-10 pins 4 mm x 4 mm, and SON-10 pins 3 mm x 3 mm packages.

The half-bridge buck converter evaluation board described in this document is designed as a test platform for evaluating the performance of 2EDL8034\_G3C. For evaluation of different packages, evaluation boards are available as shown in [Table 1](#).

**Table 1 Board specifications**

Part number	Package	Body size	Evaluation board
<a href="#">2EDL803x-G3C</a>	PG-VDSO-10-4	3 mm x 3 mm	<a href="#">EVAL_HB_2EDL803x-G3C</a>
<a href="#">2EDL803x-G4B</a>	PG-VSON-8-5	4 mm x 4 mm	<a href="#">EVAL_HB_2EDL803x-G4B</a>
<a href="#">2EDL803x-G4C</a>	PG-VDSO-10-2	4 mm x 4 mm	<a href="#">EVAL_HB_2EDL803x-G4C</a>

### Intended audience

Power supply designers, component engineers, hardware engineers, etc.

## Table of contents

<b>About this document.....</b>	<b>1</b>
<b>Table of contents.....</b>	<b>2</b>
<b>1 Introduction.....</b>	<b>3</b>
<b>2 Getting started with the hardware.....</b>	<b>4</b>
2.1 Evaluation board.....	4
2.2 List of connection and test points.....	5
2.3 Quick start guide.....	5
<b>3 Test results.....</b>	<b>6</b>
<b>4 Footprint selection for different FETs.....</b>	<b>9</b>
<b>5 Addendum.....</b>	<b>12</b>
5.1 Schematic.....	12
5.2 Layout.....	15
5.3 Bill of materials (BOM).....	17
<b>Revision history.....</b>	<b>18</b>

Introduction

# 1 Introduction

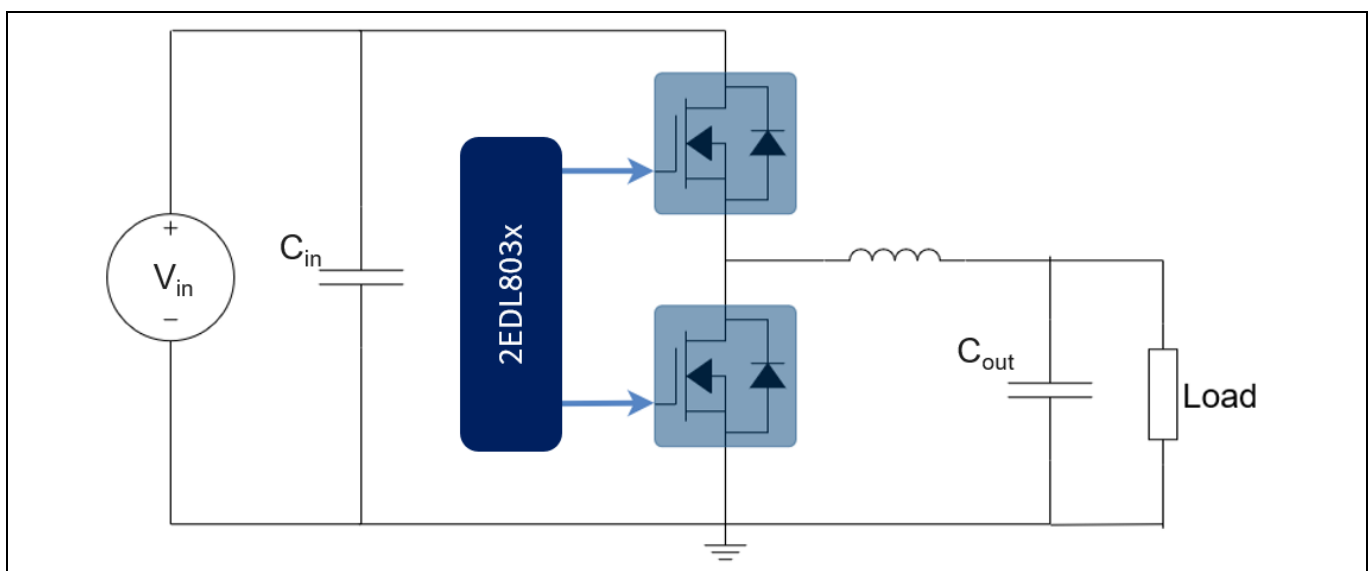
The evaluation board provides the design engineer with a test platform for evaluating the performance of the 2EDL8034 gate driver – such as, but not limited to, its propagation delay, delay matching, and rise/fall time characteristics. The influence of the surrounding gate drive circuitry such as the external gate resistors on the MOSFET’s switching behavior can also be evaluated. The board is configured as a half-bridge buck converter in an open-loop configuration and tested with 48 V typical input voltage and 12 V typical output voltage. The Infineon components used in this evaluation board are:

- EiceDRIVER™ 2EDL8034 as half-bridge driver for the low-side and high-side MOSFET
- OptiMOS™ 100 V 4 mΩ (BSC040N10NS5) in SuperSO8 package as the power MOSFET

**Table 2** shows the typical board electrical specifications, but the user has the freedom to vary the input voltage (60 V maximum), output voltage, output current, switching frequency and dead time, because the board is configured in open-loop configuration. Care must be taken not to exceed the components’ maximum voltage ratings and current ratings (e.g., the inductor’s saturation current rating), as well as the devices’ temperature ratings. Provide adequate airflow or forced air if necessary.

**Table 2 Board specifications**

Parameter	Symbol	Value	Unit
Input voltage	$V_{in}$	48	V
Output voltage	$V_{out}$	12	V
Output current	$I_{out}$	0 to 8	A
Switching frequency	$F_{sw}$	200	kHz
Dead time	$DT_{on}, DT_{off}$	100	ns
Board dimensions	88.0 mm (L) x 60.5 mm (W)		



**Figure 1 Block diagram of EVAL\_HB\_2EDL803x**

## Getting started with the hardware

### 2 Getting started with the hardware

#### 2.1 Evaluation board

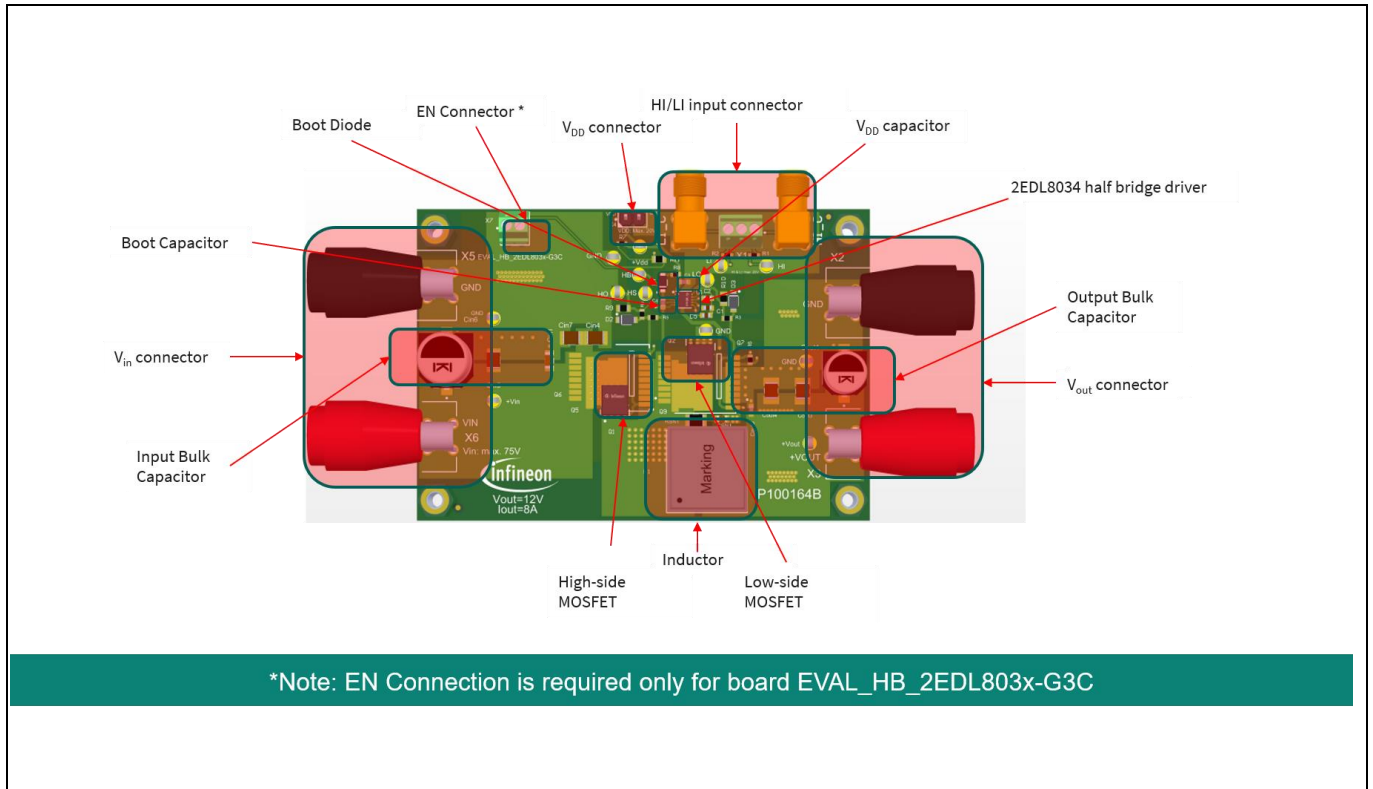


Figure 2 EVAL\_HB\_2EDL803x – top side

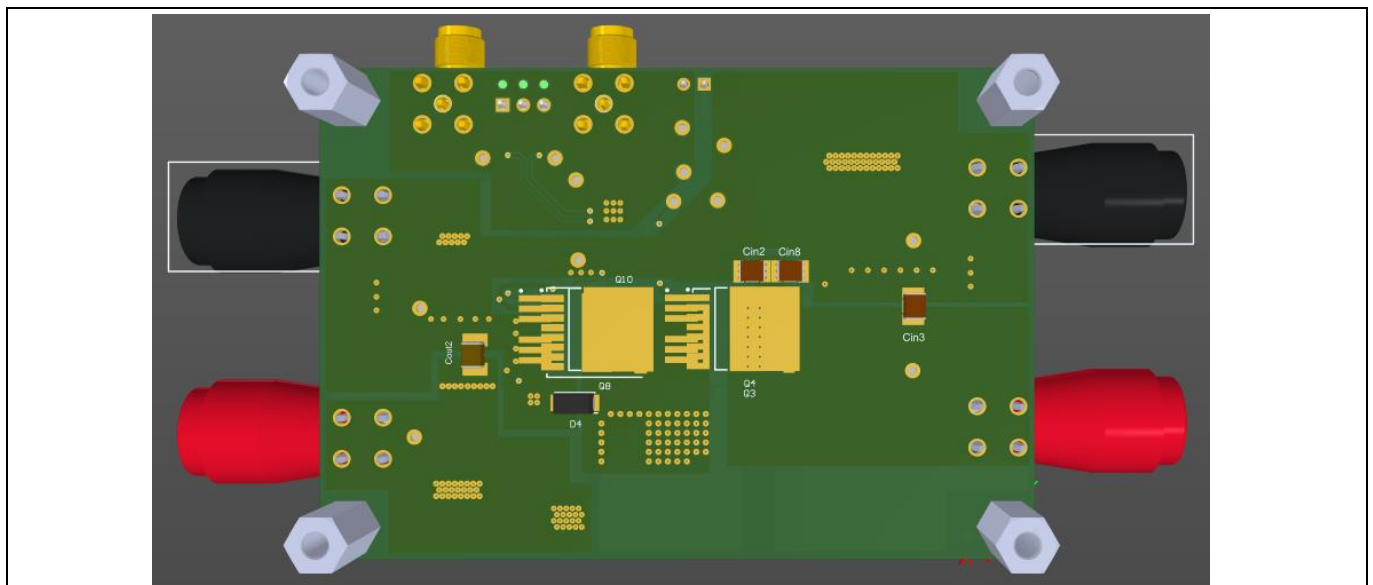


Figure 3 EVAL\_HB\_2EDL803x – bottom side

### 2.2 List of connection and test points

**Table 3 Connection and test points – functional descriptions**

Connection/test point	Description
X1	HI and LI PWM input
X2	Input GND
X3	V <sub>out</sub> connector
X4	V <sub>DD</sub> connector
X5	Output GND
X6	V <sub>in</sub> connector
X7*	EN connector
+V <sub>in</sub>	V <sub>in</sub> sense point
+V <sub>out</sub>	V <sub>out</sub> sense point

Note: EN connector (X7) is only available on board EVAL\_2EDL803x-G3C

### 2.3 Quick start guide

1. Input the PWM signals (LI and HI) using a function generator with the desired pulse width, dead time and frequency through connector X1. Ensure that there is sufficient dead time to avoid cross-conduction of the two MOSFETs.
2. Supply V<sub>DD</sub> voltage using an external auxiliary power supply between 8 V and 17 V through connector X4.
3. For 2EDL803x-G3C, enable signal should be supplied between 3 V and V<sub>DD</sub> + 0.3 V through connector X7. Other drivers don't require enable signal.
4. Supply the V<sub>in</sub> voltage using an external power supply with 48 V (60 V maximum) through connector X6 (V<sub>in</sub>) and X2 (GND). If verifying the gate driver IC characteristics only, such as propagation delay, there is no need to supply the V<sub>in</sub> voltage. In this case, the HS pin must be shorted to GND in order to have a charging path for the bootstrap capacitor.
5. Connect the V<sub>out</sub> to the electronic load through connector X3 (V<sub>out</sub>) and X5 (GND) and increase the output current up to 8 A maximum. Care must be taken not to exceed the inductor's saturation limit.
6. The V<sub>DD</sub>, LI, HI, LO, and HS pin of the gate driver can be measured by a low-voltage single-ended probe, while the HO-HS and HB-HS should be measured using low-voltage differential probes. Probing loops should be as short as possible to avoid any induced ringing, and probes should be placed near the driver pins to ensure accurate measurement of the driver's performance.
7. To power down the board, turn off the load first and then turn off the input voltage supply. Then turn off the enable signal in the case of 2EDL80x-G3C. Finally, turn off the driver bias supply.

## Test results

### 3 Test results

Figure 4 and Figure 5 show the falling and rising propagation delay of the low-side and high-side drives with the  $V_{DD}$  bias supplied and  $V_{in} = 48\text{ V}$  with no load on output.

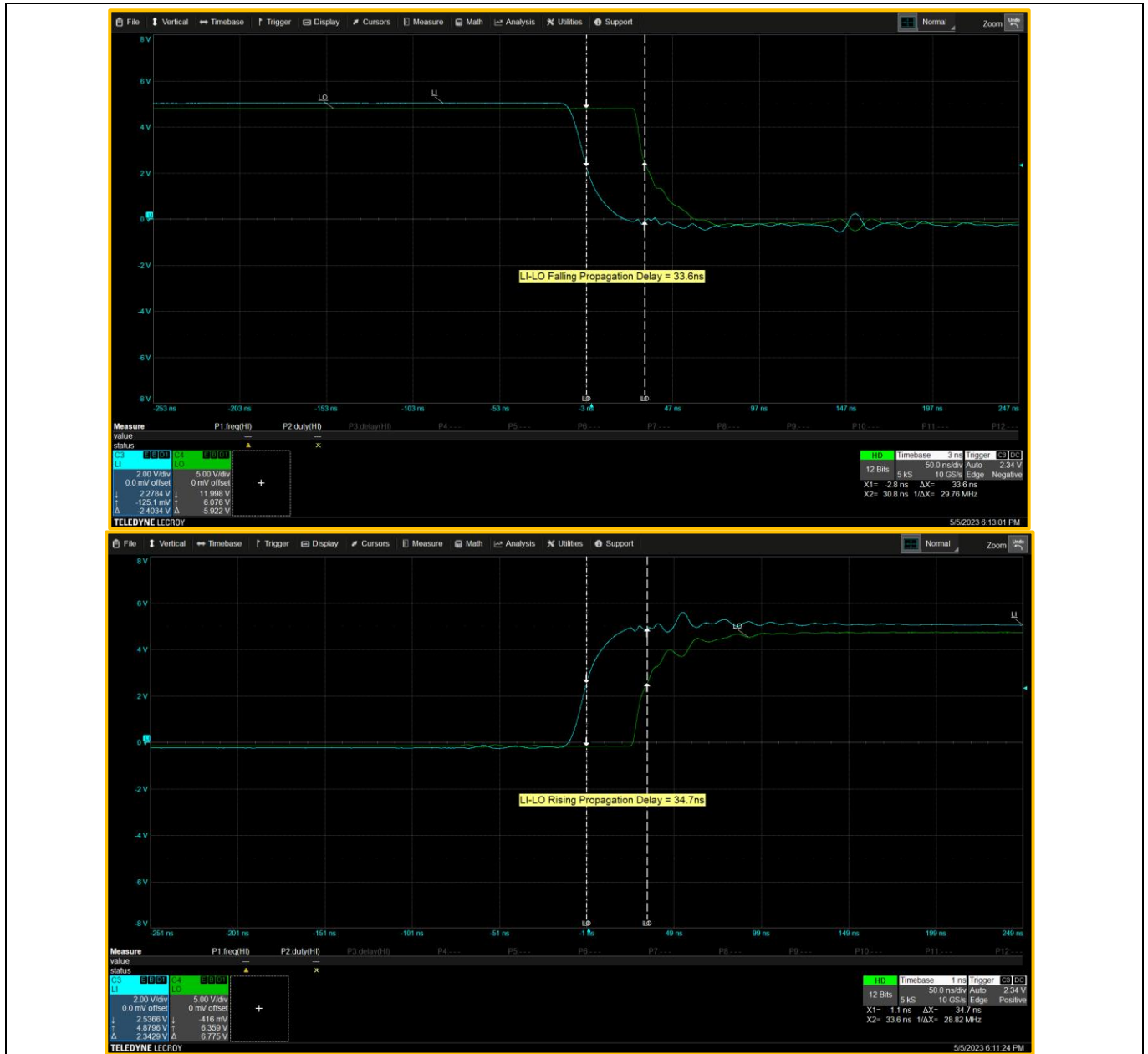
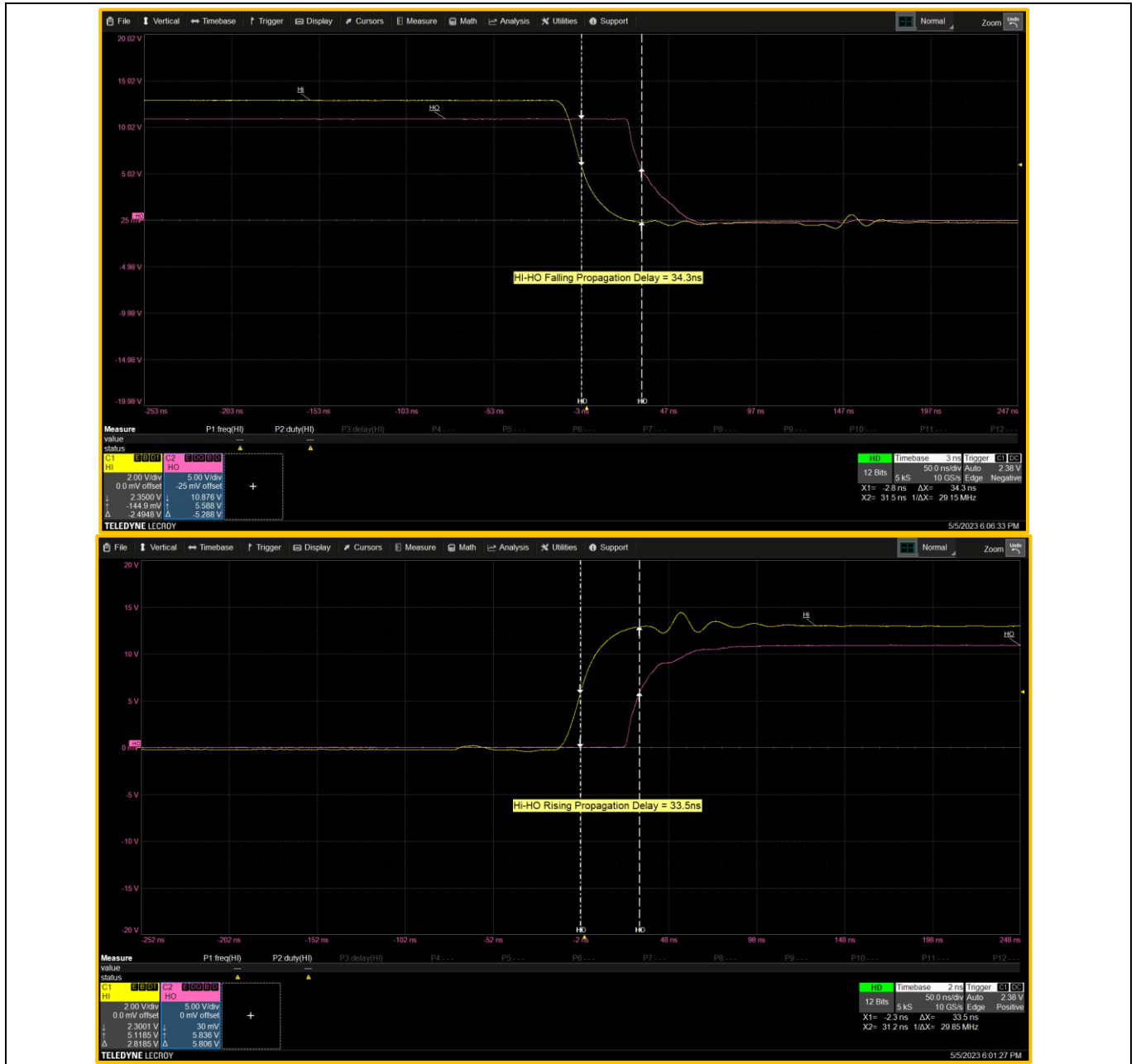


Figure 4 LI-LO falling (33.6 ns) and rising (34.7 ns) propagation delay ( $V_{DD} = 12\text{ V}$ ,  $V_{in} = 48\text{ V}$ ,  $C_{load} = 4.1\text{ nF}$ )

## Test results



**Figure 5** HI-HO falling (34.3 ns) and rising (33.5 ns) propagation delay ( $V_{DD} = 12\text{ V}$ ,  $V_{in} = 48\text{ V}$ ,  $C_{load} = 4.1\text{ nF}$ )

**Figure 6** shows the high-side and low-side output waveforms together with the switch node waveforms at  $V_{in} = 48\text{ V}$ ,  $V_{DD} = 12\text{ V}$ , duty = 23 percent,  $F_{sw} = 200\text{ kHz}$ , load = 8 A, and  $T_A = 25^\circ\text{C}$ .

## Test results



Figure 6 LO (green), HO (pink), HS (yellow) waveforms



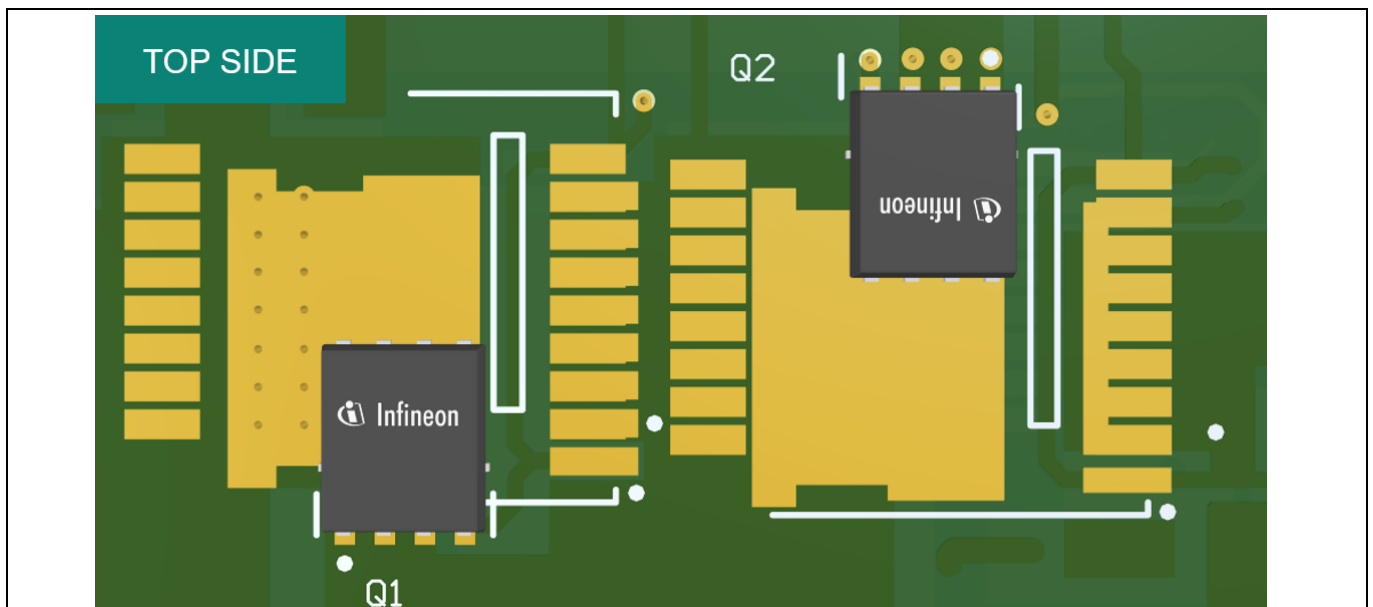
## Footprint selection for different FETs

### 4 Footprint selection for different FETs

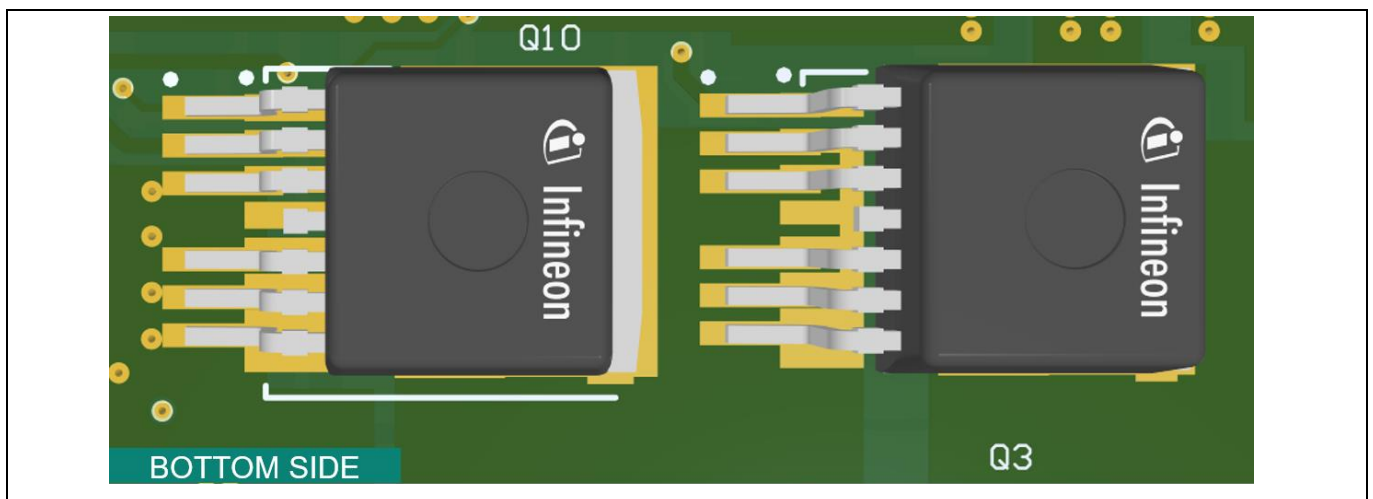
The evaluation board allows the user to test the performance of the driver IC with different FETs available in various footprints. [Table 4](#) lists all the footprints supported on this board.

**Table 4 FET footprints supported on the evaluation board**

Package	Ref. designator	Preferred FET	Figure
PG-TDSON-8-1 (SuperSO8)	Q1 and Q2	BSC040N10NS5	<a href="#">Figure 7</a>
T0263-7-3	Q3 and Q10	IPB032N10N5	<a href="#">Figure 8</a>
PG-HSOF-8-1	Q4 and Q9	IPT020N10N3	<a href="#">Figure 9</a>
PG-HSOG-8-1	Q5 and Q8	IAUS300N10S5N014	<a href="#">Figure 10</a>
PG-HDSOP-16-2	Q6 and Q7	IAUS260N10S5N019T	<a href="#">Figure 11</a>



**Figure 7 PG-TDSON-8-1 (SuperSO8) package**



**Figure 8 T0263-7-3 package**

# Half-bridge buck converter evaluation board using the EiceDRIVER™ 2EDL803x



## Footprint selection for different FETs

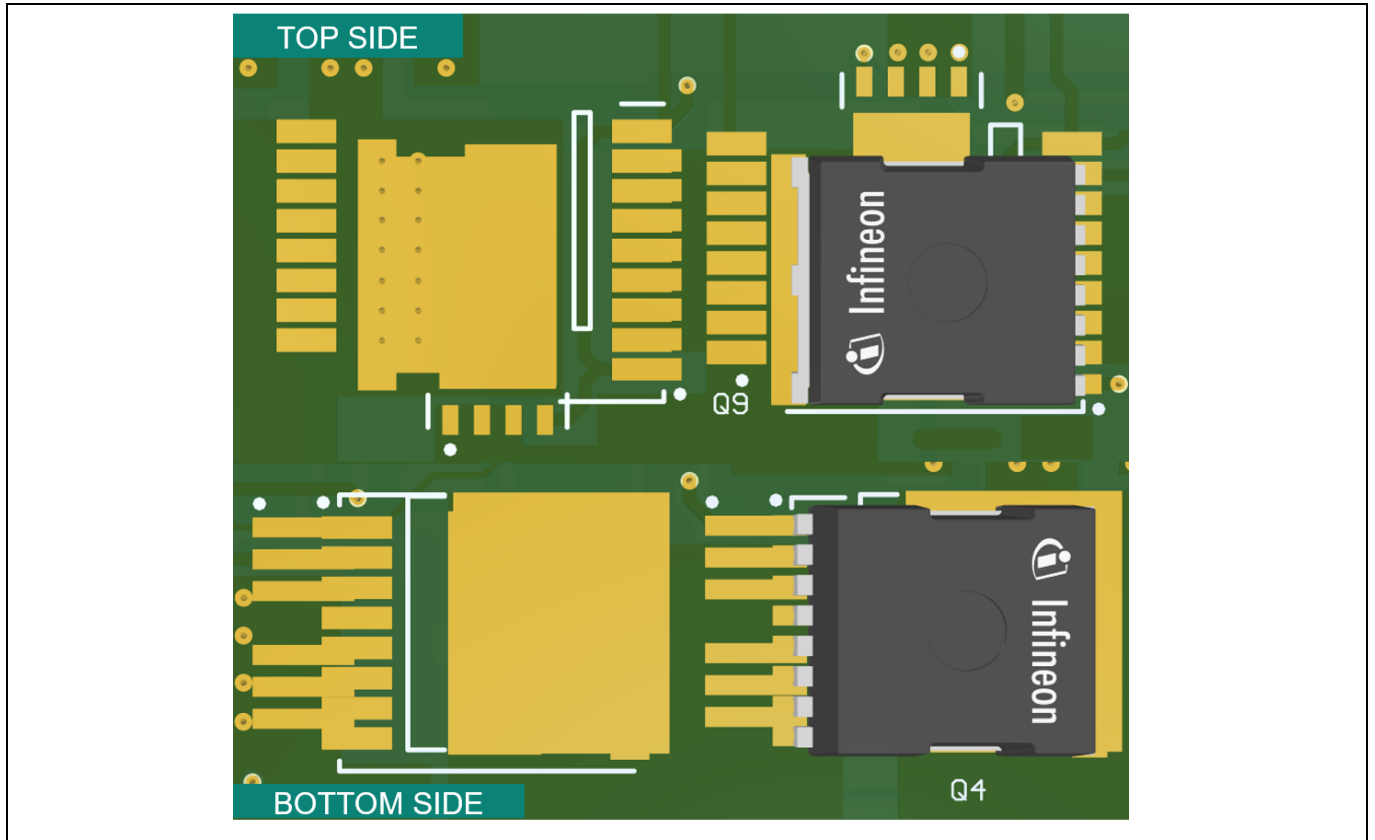


Figure 9 PG-HSOF-8-1 package

Footprint selection for different FETs

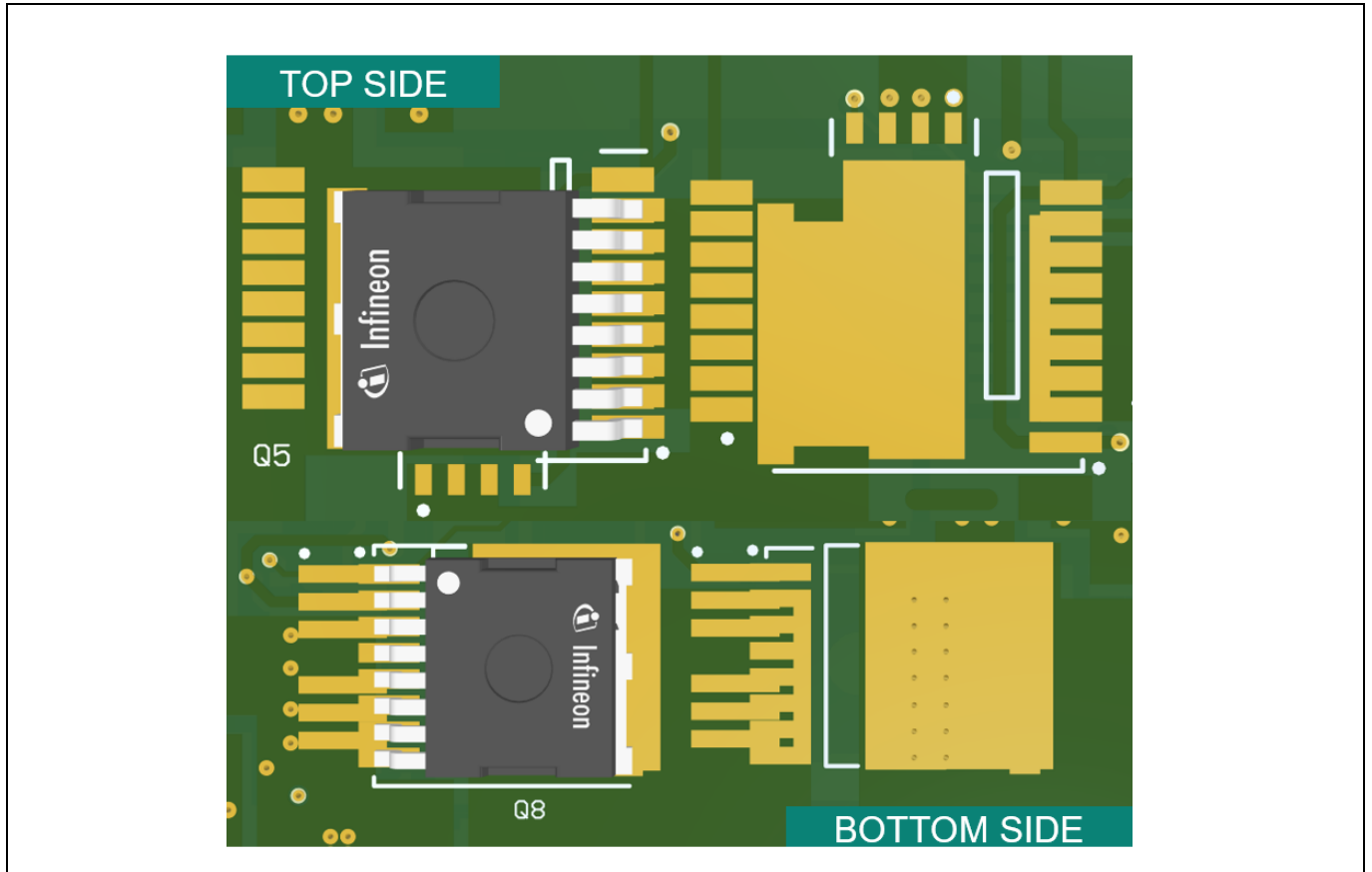


Figure 10 PG-HSOG-8-1 package

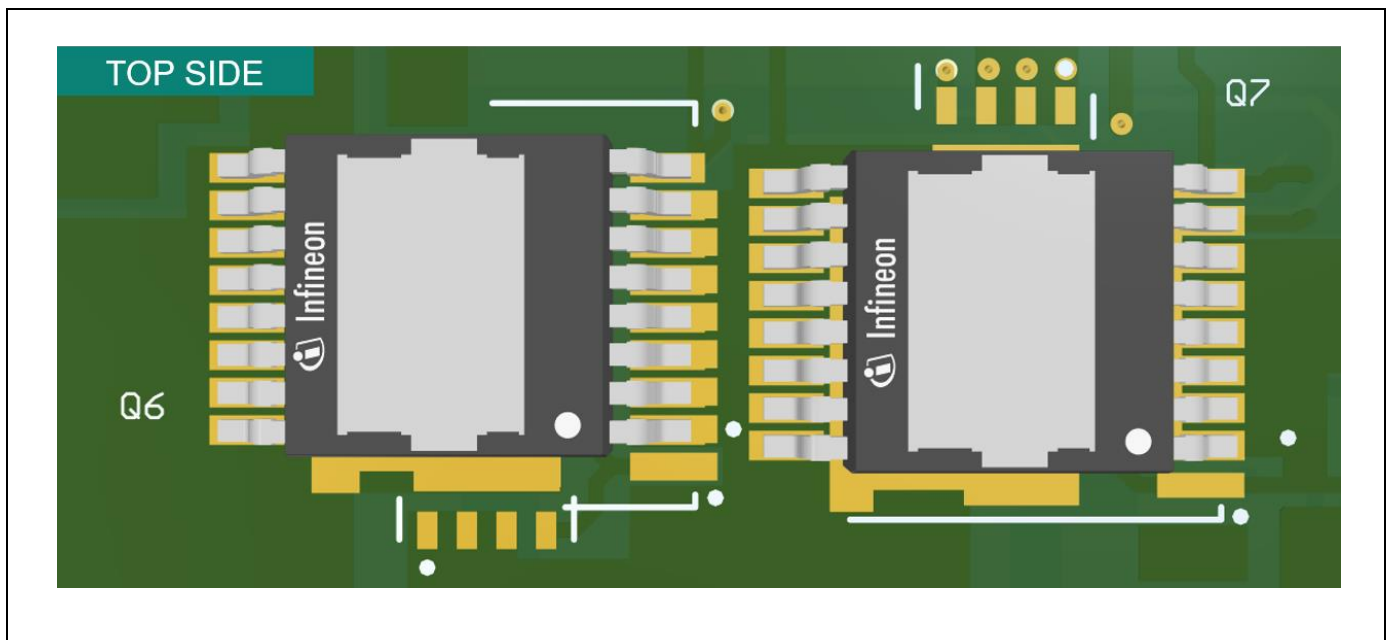


Figure 11 PG-HDSOP-16-2 package

Addendum

5 Addendum

5.1 Schematic

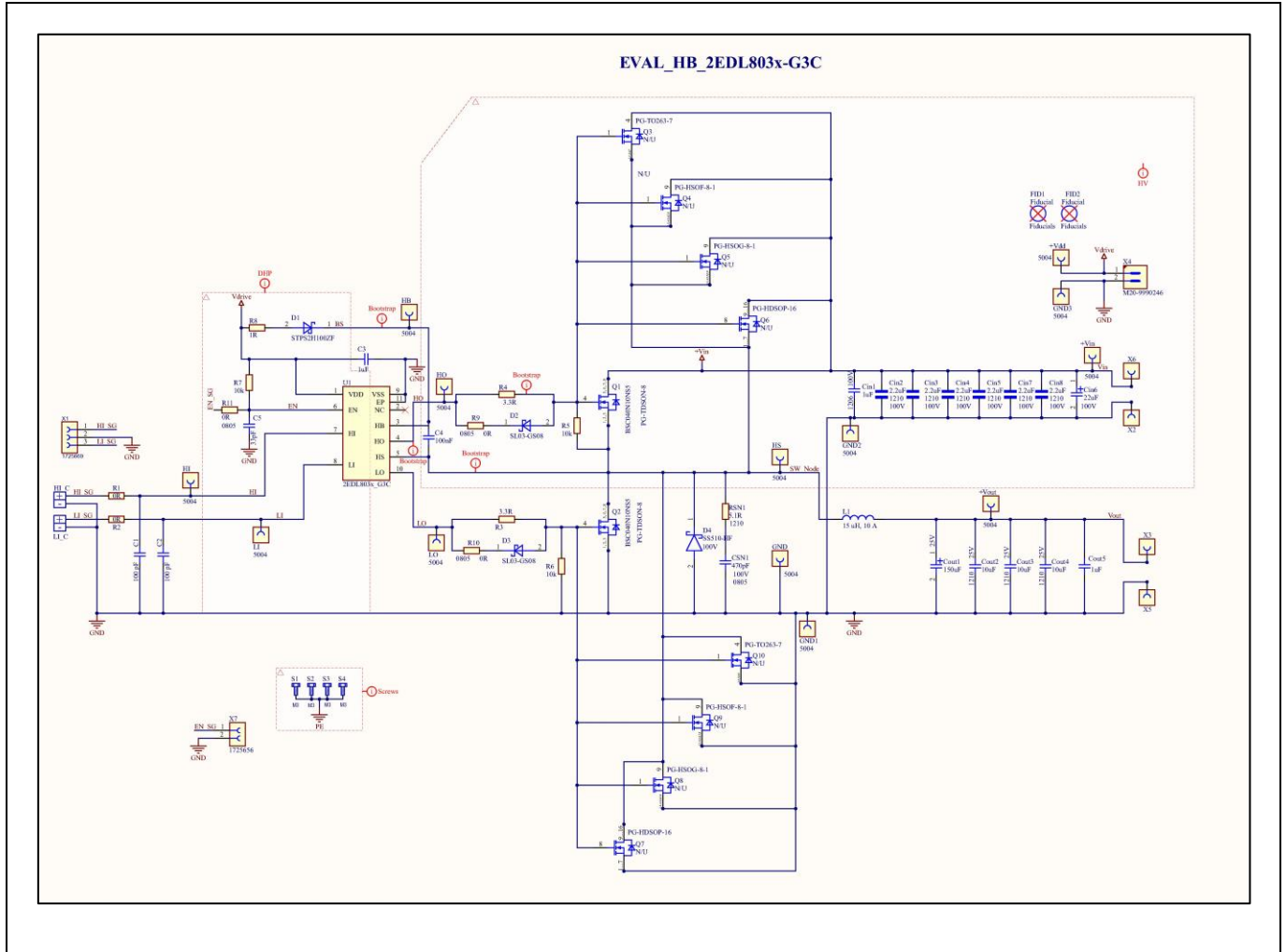


Figure 12 EVAL\_HB\_2EDL803x-G3C board schematic

## Addendum

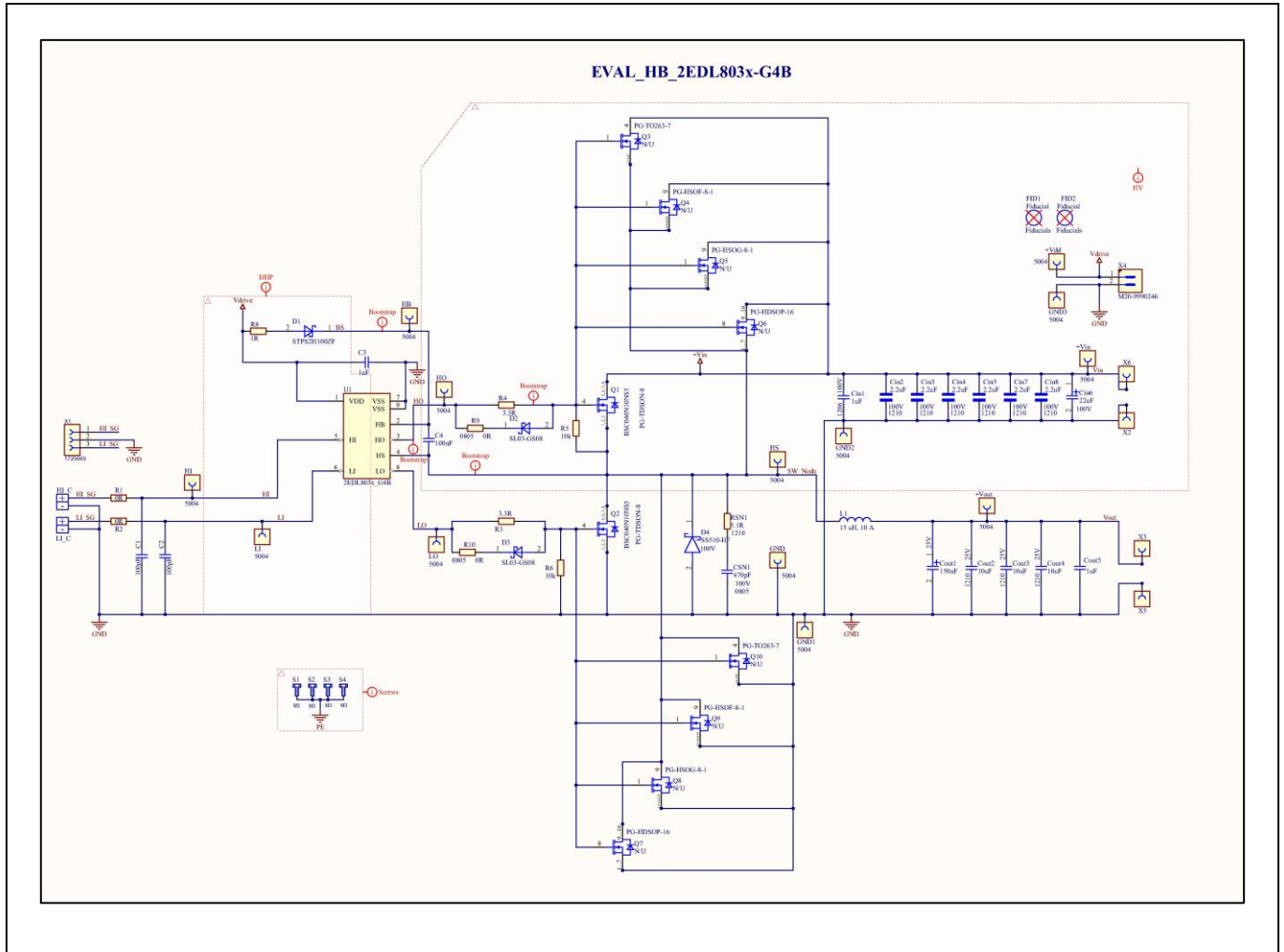


Figure 13 EVAL\_HB\_2EDL803x-G4B board schematic

## Addendum

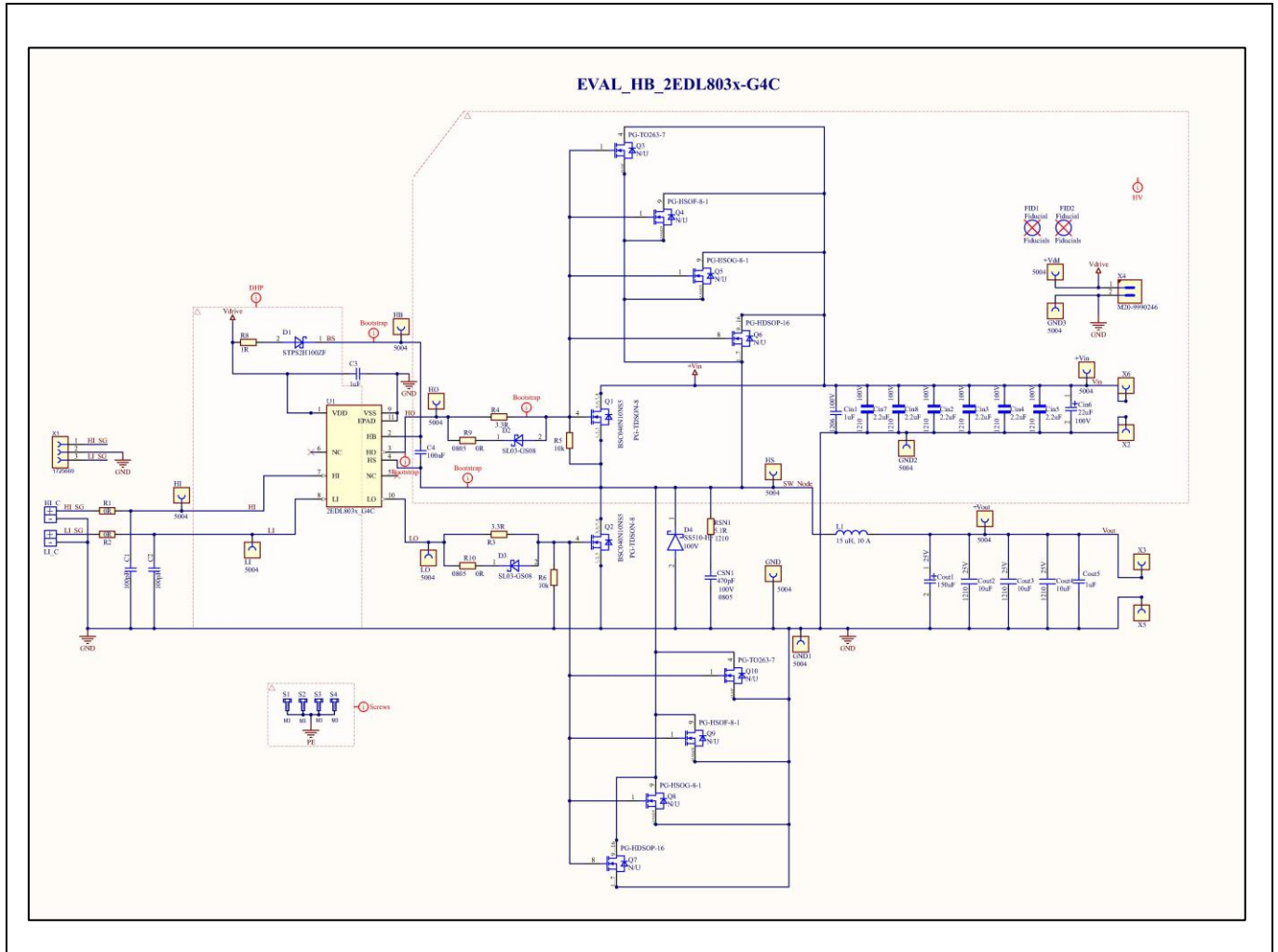


Figure 14 EVAL\_HB\_2EDL803x-G4C board schematic

## 5.2 Layout

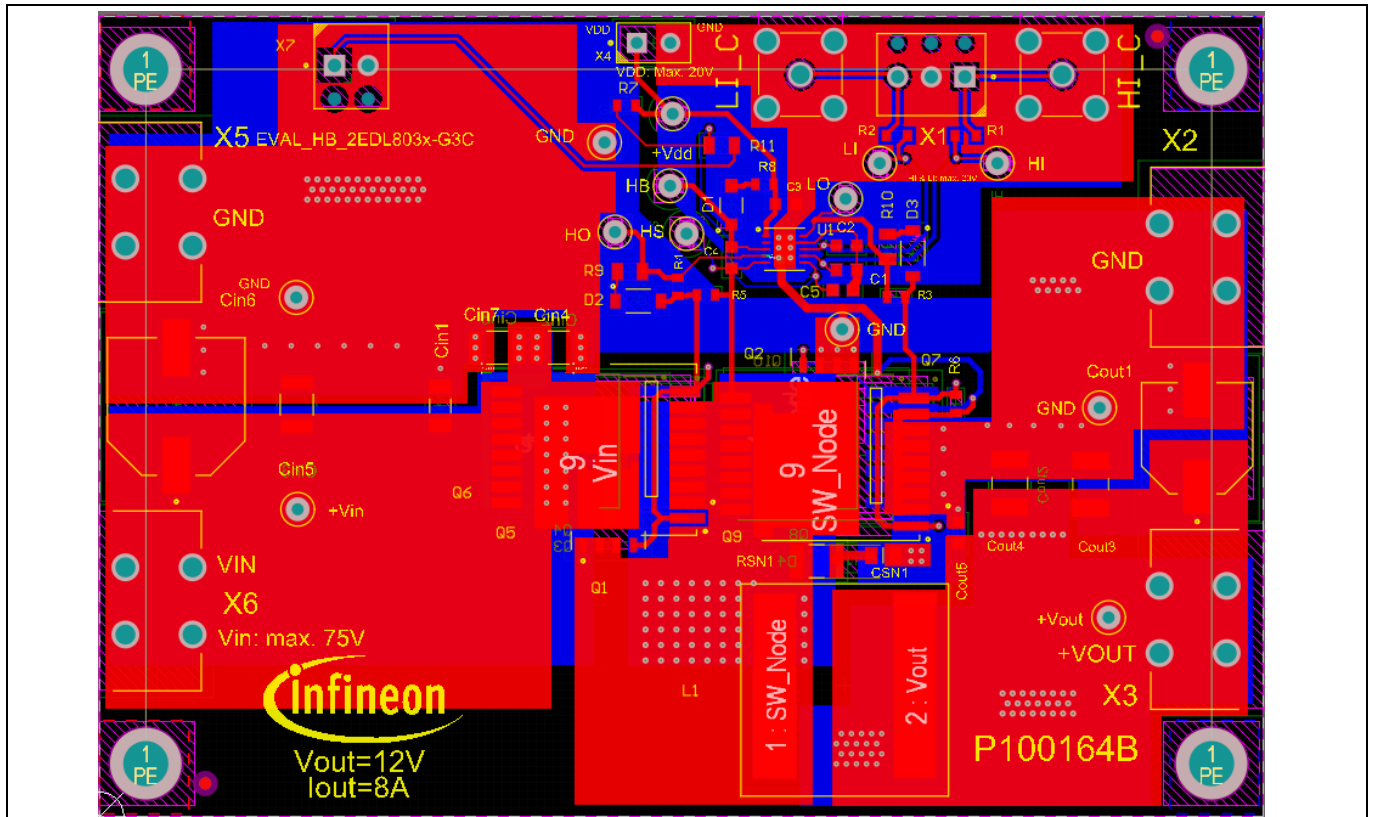


Figure 15 EVAL\_HB\_2EDL803x-G3C board layout

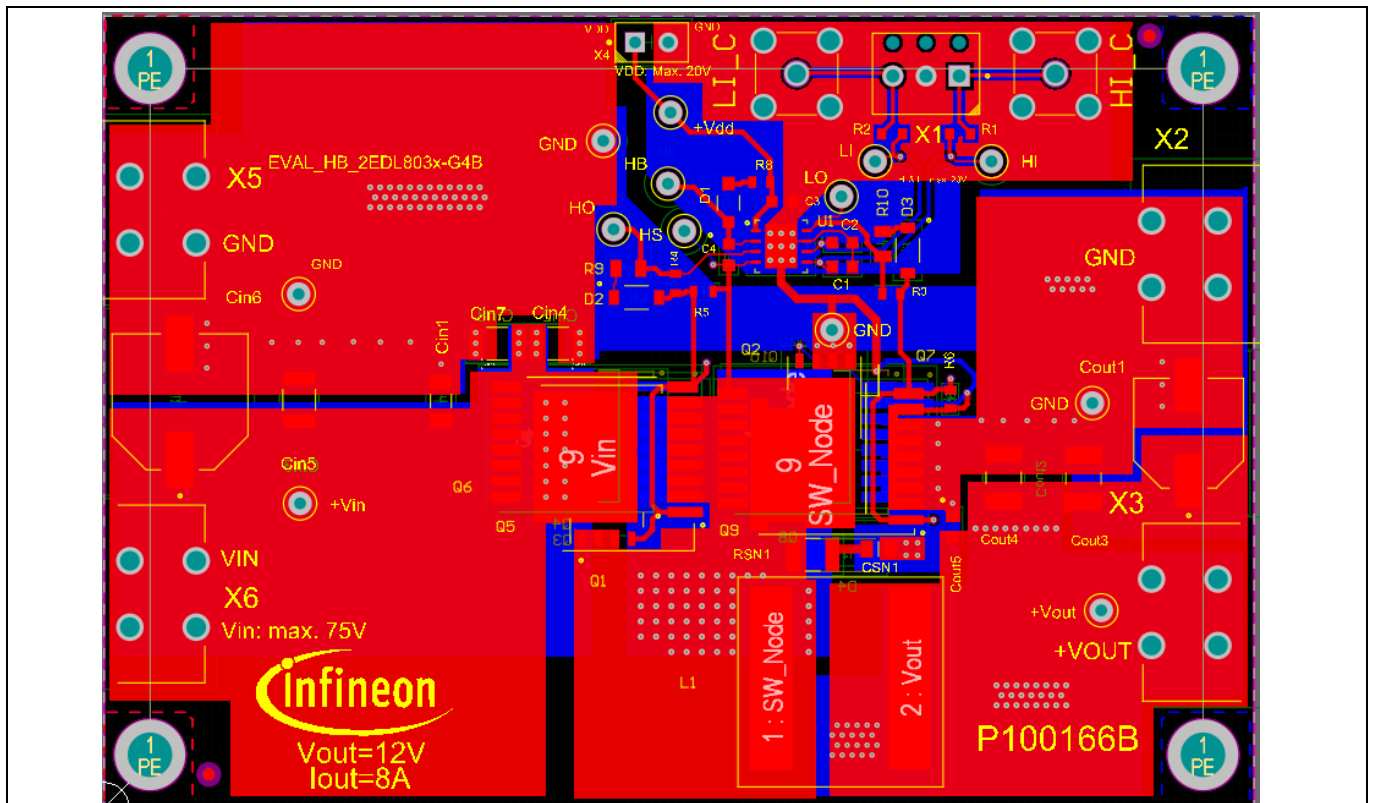


Figure 16 EVAL\_HB\_2EDL803x-G4B board layout

Addendum

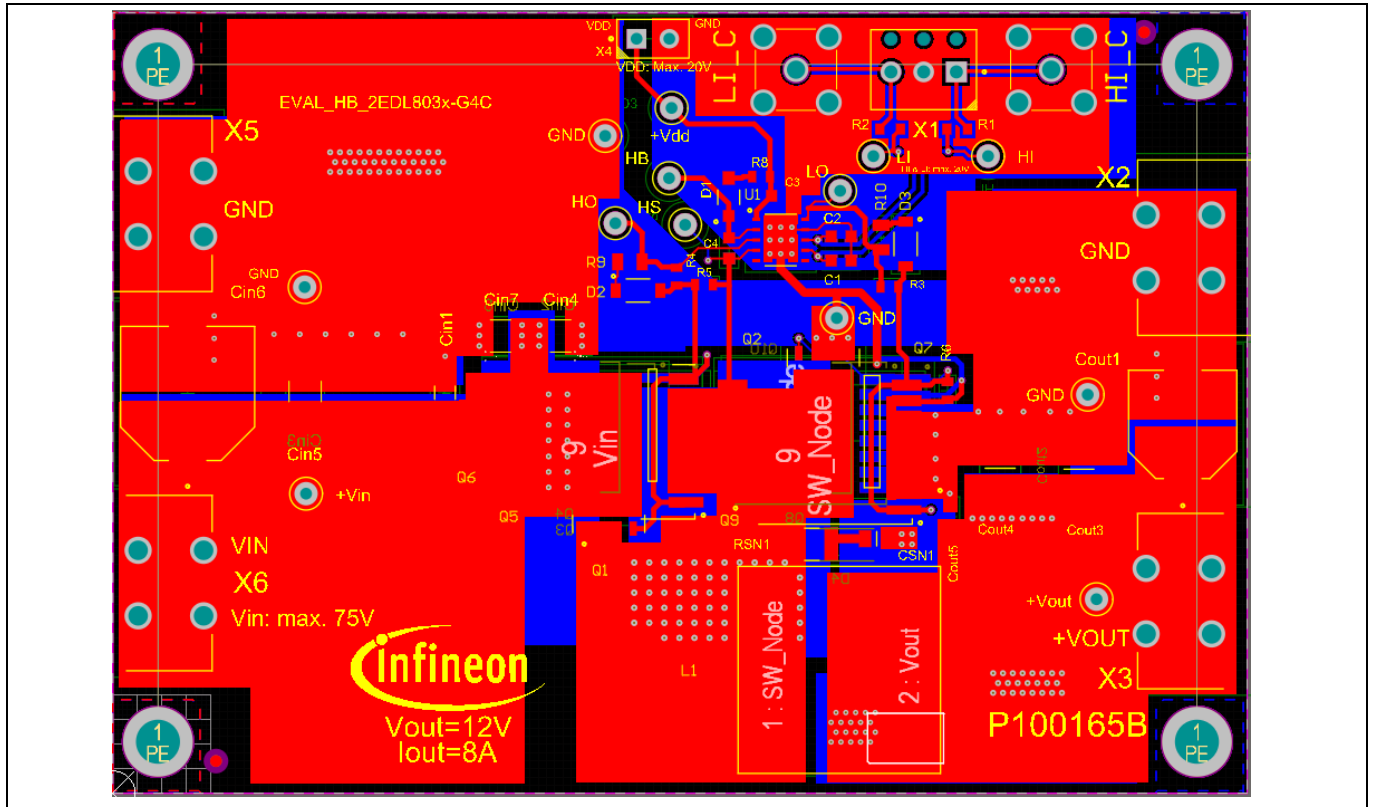


Figure 17 EVAL\_HB\_2EDL803x-G4C board layout



# Half-bridge buck converter evaluation board using the EiceDRIVER™ 2EDL803x



## Addendum

### 5.3 Bill of materials (BOM)

Designator	Value	Part Description	Package	Manufacturer	Manufacturer Order Number
+Vdd, +Vin, +Vout, GND, HB, HI, HO, HS, LI, LO, GND1, GND2, GND3	5004	Circuit Board Hardware - PCB TEST POINT YELLOW		Keystone	5004
C1, C2	100 pF	MLCC - X7R - 25V	0603	MuRata	GCM033R71E101KA03
C5*	33 pF	MLCC - X7R - 25V	0603	Kemet	C0603C330K3RACTU
C3, Cout5	1 µF	MLCC - X7R - 25V	0603	Samsung	CL10B105KA8VPNC
C4	100 nF	MLCC - X5R - 25V	CAPC1608X90N	Kemet	C0603C104K3PAC7867
Cin1	1 µF	MLCC - X7R - 100V	1206	MuRata	GRM31CR72A105KA01
Cin2, Cin3, Cin4, Cin5, Cin7, Cin8	2.2 uF	MLCC - X7R - 100V	1210	TDK Corporation	C3225X7R2A225K230AB
Cin6	22 µF	Al Polymer Cap	Radial: 10x12.6mm	Panasonic	1005XV22M
Cout1	150 µF	Al Polymer Cap	SMD	Kemet	A768KE157M1ELAE029
Cout2, Cout3, Cout4	10 µF	MLCC - X7R - 25V	1210	MuRata	GRM32DR71E106KA12K
CSN1	470 pF	MLCC - COG - 100V	0805	MuRata	GRM219R72A471KA01
D1	STPS2H100ZF	Schottky Barrier Diode 100 V - 2 A	SOD123 Flat	STMicroelectronics	STPS2H100ZF
D2, D3	SL03-GS08	Schottky Diodes & Rectifiers 1.1A .395V	DO-219AB (SMF)	Vishay	SL03-GS08
D4	SS510-HF	Schottky Barrier Diode 100 V - 5 A	DO-214AC (SMA)	Comchip Technology	SS510-HF
HL_C, LI_C		RF Connectors / Coaxial Connectors SMA R/A JACK PCB DIECAST		Amphenol RF	132225
L1	15 µH	15 µH Shielded Drum Core, Wirewound Inductor 10 A 11.3 mΩ Nonstandard		Wuerth Elektronik	74439370150
Q1, Q2	BSC040N10NS5	OptiMOS5 Power-MOSFET 100V 4mΩ	PG-TDSON-8-1	Infineon Technologies	BSC040N10NS5
R1, R2	0R	Standard Thick Film Chip Resistor	0603	Yageo	AC0603FR-070RL
R3, R4	3.3R	General Purpose Chip Resistor	0603	Yageo	RT0603FRD073R3L
R5, R6, R7*	10K	Standard Thick Film Chip Resistor	0603	Yageo	RC0603FR-0710KL
R8	1R	Standard Thick Film Chip Resistor	0603	Vishay	CRCW06031R00FK
R9, R10, R11*	0R	Standard Thick Film Chip Resistor	0805	Yageo	RC0805FR-070RL, RC0805JR-070RL
RSN1	5.1R	Standard Thick Film Chip Resistor	1210	Panasonic	ERJ-14VJ5R1U
U1*	2EDL8034_G3C	EiceDRIVER™ 2EDL803x, Junction-Isolated High-Side and Low-Side gate driver IC	PG-VSON-10-4	Infineon Technologies	2EDL8034_G3C
X1	1725669	Fixed Terminal Blocks 3P 2.54mm 90DEG		Phoenix Contact	1725669
X5, X2	CT3151SP-0	Test Plugs & Test Jacks SafetyJack,Horz PCB, Black		Cal Test Electronics	CT3151SP-0
X3, X6	CT3151SP-2	Test Plugs & Test Jacks SafetyJack,Horz PCB, Red		Cal Test Electronics	CT3151SP-2
X4	M20-9990246	Headers & Wire Housings 02 SIL VERTICAL PIN HEADER TIN		Harwin	M20-9990246
X7*	1725656	Fixed Terminal Blocks 2P 2.54mm 90DEG		Phoenix Contact	1725656

\*Note: For other eval boards, U1 used is the corresponding gate driver IC Package and C5, R7, R11 and X7 are not available

**Figure 18 EVAL\_HB\_2EDL803x board BOM**

Revision history

Revision history

Document version	Date of release	Description of changes
V 1.0	2023-06-07	Initial release

**Trademarks**

All referenced product or service names and trademarks are the property of their respective owners.

**Edition 2023-06-07**

**Published by**

**Infineon Technologies AG**

**81726 Munich, Germany**

**© 2023 Infineon Technologies AG.**

**All Rights Reserved.**

**Do you have a question about this document?**

**Email: [erratum@infineon.com](mailto:erratum@infineon.com)**

**Document reference**

**UM\_2305\_PL88\_2305\_223554**

**IMPORTANT NOTICE**

The information contained in this application note is given as a hint for the implementation of the product only and shall in no event be regarded as a description or warranty of a certain functionality, condition or quality of the product. Before implementation of the product, the recipient of this application note must verify any function and other technical information given herein in the real application. Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind (including without limitation warranties of non-infringement of intellectual property rights of any third party) with respect to any and all information given in this application note.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

For further information on the product, technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies office ([www.infineon.com](http://www.infineon.com)).

**WARNINGS**

Due to technical requirements products may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies office.

Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Power Management IC Development Tools](#) category:*

*Click to view products by [Infineon](#) manufacturer:*

Other Similar products are found below :

[EVB-EP5348UI](#) [DA9063-EVAL](#) [BQ24155EVM](#) [BQ25010EVM](#) [REG710EVM-5](#) [TPS54980EVM-022](#) [TPS65010EVM-230](#) [BQ24120EVM-001](#) [BQ24212EVM-678](#) [BQ3050EVM-001](#) [ISL9520EVAL1Z](#) [UCC3809EVM](#) [LM3691TL-1.2EV/NOPB](#) [SOT23-3EV-VREG](#) [SOT89-3EV-VREG](#) [TPS2458EVM](#) [TPS54229EEVM-056](#) [TPS54329EEVM-056](#) [MAX8556EVKIT](#) [MAX20012EVKIT#](#) [MAX15005AEVKIT+](#) [S6SBP203A8FVA1001](#) [TPS652510EVM](#) [STEVAL-ISA047V1](#) [ISL8502AEVAL1Z](#) [ISL8009AEVAL1Z](#) [TPS76901EVM-127](#) [FRDM-HB2001-EVM](#) [BM6208FS-EVK-001](#) [LM5115EVAL](#) [LP5900TL-2.5EV](#) [DRI0043](#) [7E.12.8.230.0002](#) [KITPF8100FRDMEVM](#) [NCP10671B05GEVB](#) [MAX20073EVKIT#](#) [EVB-EN6337QA](#) [AP3125AEV1](#) [NIV6350MT2GEVB](#) [XMCA1](#) [RD33771-48VEVM](#) [EVKT-MPM3695-10-A](#) [DEMO200W12VDCLLC](#) [SAMPLEBOXILD8150TOBO1](#) [MAX18066EVKIT#](#) [AP61100Z6-EVM](#) [AP62300WU-EVM](#) [KIT8020-CRD-8FF1217P-1](#) [KITPF8121FRDMEVM](#) [EV2174C-G-00A](#)